VS-15ETH06HN3

Vishay Semiconductors



Hyperfast Rectifier, 15 A Fred Pt[®]



| PRIMARY CHARACTERISTICS | | | | | | | | |
|----------------------------------|----------|--|--|--|--|--|--|--|
| I _{F(AV)} | 15 A | | | | | | | |
| V _R | 600 V | | | | | | | |
| V _F at I _F | 1.3 V | | | | | | | |
| t _{rr} typ. | 22 ns | | | | | | | |
| T _J max. | 175 °C | | | | | | | |
| Package | TO-220AC | | | | | | | |
| Circuit configuration | Single | | | | | | | |

FEATURES

- Hyperfast recovery time
- Low forward voltage drop
- 175 °C operating junction temperature
- Low leakage current
- Single die center tap module



COMPLIANT

- AEC-Q101 qualified, meets JESD 201 class 2 HALOGEN FREE whisker test
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

DESCRIPTION / APPLICATIONS

State of the art hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

Their extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

| ABSOLUTE MAXIMUM RATINGS | | | | | | | | | | |
|---|-----------------------------------|-------------------------|-------------|-------|--|--|--|--|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | VALUES | UNITS | | | | | | |
| Peak repetitive reverse voltage | V _{RRM} | | 600 | V | | | | | | |
| Average rectified forward current | I _{F(AV)} | T _C = 137 °C | 15 | | | | | | | |
| Non-repetitive peak surge current | I _{FSM} | T _J = 25 °C | 120 | А | | | | | | |
| Peak repetitive forward current | I _{FM} | | 30 | | | | | | | |
| Operating junction and storage temperatures | T _J , T _{Stg} | | -65 to +175 | °C | | | | | | |

| ELECTRICAL SPECIFICATIONS ($T_J = 25 \ ^{\circ}C$ unless otherwise specified) | | | | | | | | | | |
|---|--------------------|---|------|------|-------|----|--|--|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | TYP. | MAX. | UNITS | | | | | |
| Breakdown voltage, blocking voltage | V_{BR} , V_{R} | I _R = 100 μA | 600 | - | - | | | | | |
| Forward voltage | V _F | I _F = 15 A | - | 1.8 | 2.2 | V | | | | |
| | | I _F = 15 A, T _J = 150 °C | - | 1.3 | 1.6 | | | | | |
| Reverse leakage current | I _R | V _R = V _R rated | - | 0.2 | 50 | | | | | |
| | | $T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$ - 3 | | 30 | 500 | μA | | | | |
| Junction capacitance | CT | V _R = 600 V | - | 20 | - | pF | | | | |
| Series inductance | L _S | Measured lead to lead 5 mm from package body | - | 8.0 | - | nH | | | | |

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| DYNAMIC RECOVERY CHARACTERISTICS (T _C = 25 °C unless otherwise specified) | | | | | | | | | |
|---|------------------|---|---|------|------|------|-------|--|--|
| PARAMETER | SYMBOL | TEST CO | NDITIONS | MIN. | TYP. | MAX. | UNITS | | |
| | | $I_F = 1 \text{ A}, \text{ d}I_F/\text{d}t = 100 \text{ A}/\mu\text{s}, \text{ V}_R = 30 \text{ V}$ | | - | 22 | - | | | |
| Reverse recovery time | + | $I_F = 15 \text{ A}, \text{ d}I_F/\text{d}t = 100$ | - | 28 | - | 20 | | | |
| neverse recovery time | t _{rr} | T _J = 25 °C | | - | 29 | - | ns | | |
| | | T _J = 125 °C | I _F = 15 A dI _F /dt = 200 A/μs V _R = 390 V | - | 75 | - | | | |
| Peak recovery current | I _{RRM} | T _J = 25 °C | | - | 3.5 | - | А | | |
| | | T _J = 125 °C | | - | 7 | - | | | |
| | Q _{rr} | T _J = 25 °C | | - | 57 | - | nC | | |
| Reverse recovery charge | | T _J = 125 °C | | - | 300 | - | | | |
| Reverse recovery time | t _{rr} | | I _F = 15 A | - | 51 | - | ns | | |
| Peak recovery current | I _{RRM} | T _J = 125 °C | dI _F /dt = 800 A/µs V _R = 390 V | - | 20 | - | А | | |
| Reverse recovery charge | Q _{rr} | | | - | 580 | - | nC | | |

| THERMAL MECHANICAL SPECIFICATIONS | | | | | | | | | |
|---|-----------------------------------|--|--------------|------|------------|------------------------|--|--|--|
| PARAMETER | SYMBOL | TEST CONDITIONS | MIN. | TYP. | MAX. | UNITS | | | |
| Maximum junction and storage temperature range | T _J , T _{Stg} | | -65 | - | 175 | °C | | | |
| Thermal resistance, junction to case | R _{thJC} | | - | 1.1 | 1.4 | | | | |
| Thermal resistance, junction to ambient per leg | R _{thJA} | Typical socket mount | - | - | 70 | °C/W | | | |
| Thermal resistance, case to heatsink | R _{thCS} | Mounting surface, flat, smooth and greased | - | 0.5 | - | | | | |
| Waisht | | | - | 2.0 | - | g | | | |
| Weight | | | - | 0.07 | - | oz. | | | |
| Mounting torque | | | 6.0 (5.0) | - | 12 (10) | kgf · cm (lbf · in) | | | |
| Marking device | | Case style TO-220AC | 15ETH06H | | | | | | |

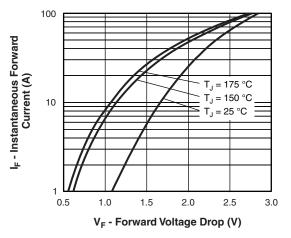
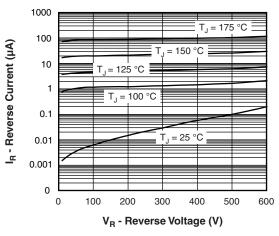
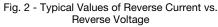


Fig. 1 - Typical Forward Voltage Drop Characteristics





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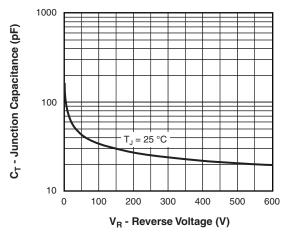
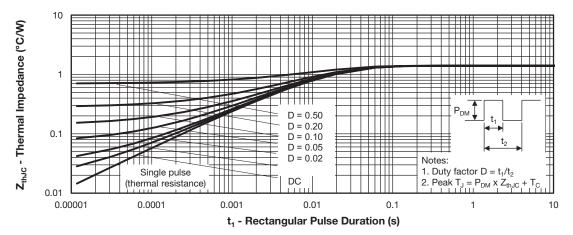
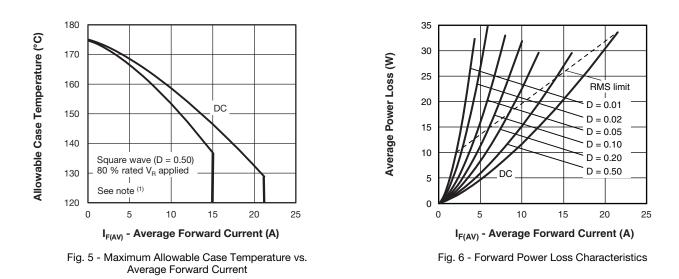


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage







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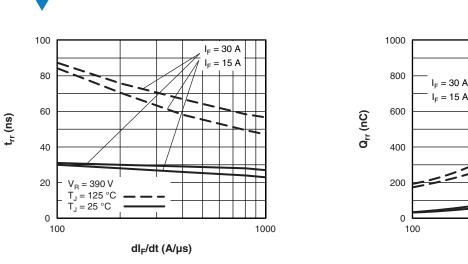


Fig. 7 - Typical Reverse Recovery Time vs. dI_F/dt

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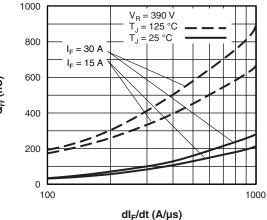


Fig. 8 - Typical Stored Charge vs. dl_F/dt

Note

SHA

- ⁽¹⁾ Formula used: $T_C = T_J (Pd + Pd_{REV}) \times R_{thJC}$;
 - $\begin{array}{l} \mathsf{Pd} = \mathsf{Forward} \ \mathsf{power} \ \mathsf{loss} = \mathsf{I}_{\mathsf{F}(\mathsf{AV})} \times \mathsf{V}_{\mathsf{FM}} \ \mathsf{at} \ (\mathsf{I}_{\mathsf{F}(\mathsf{AV})}/\mathsf{D}) \ (\mathsf{see} \ \mathsf{fig.} \ \mathsf{8}); \\ \mathsf{Pd}_{\mathsf{REV}} = \mathsf{Inverse} \ \mathsf{power} \ \mathsf{loss} = \mathsf{V}_{\mathsf{R1}} \times \mathsf{I}_{\mathsf{R}} \ (\mathsf{1} \mathsf{D}); \ \mathsf{I}_{\mathsf{R}} \ \mathsf{at} \ \mathsf{V}_{\mathsf{R1}} = \mathsf{Rated} \ \mathsf{V}_{\mathsf{R}} \end{array}$

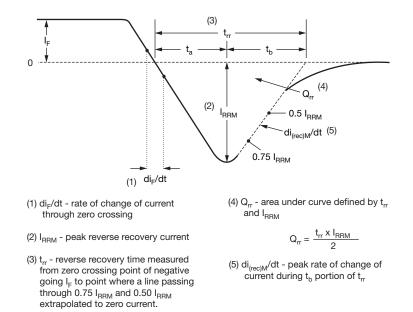


Fig. 9 - Reverse Recovery Waveform and Definitions



ORDERING INFORMATION TABLE

| ORDERING INFORMATION (Example) | | | | | | | | | |
|--------------------------------|------------------|------------------------|-------------------------|--|--|--|--|--|--|
| PREFERRED P/N | QUANTITY PER T/R | MINIMUM ORDER QUANTITY | PACKAGING DESCRIPTION | | | | | | |
| VS-15ETH06HN3 | 50 | 1000 | Antistatic plastic tube | | | | | | |

| LINKS TO RELATED DOCUMENTS | | | | | | | |
|----------------------------|-------------|--------------------------|--|--|--|--|--|
| Dimensions | TO-220AC | www.vishay.com/doc?95221 | | | | | |
| Part marking information | TO-220ACHN3 | www.vishay.com/doc?95068 | | | | | |
| SPICE model | | www.vishay.com/doc?96619 | | | | | |



TO-220AC

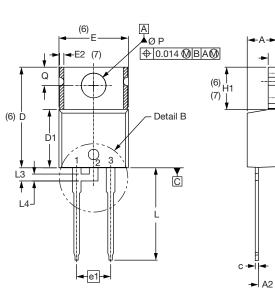
B Seating

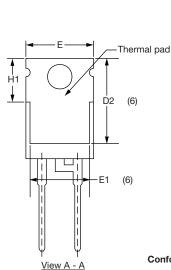
A-

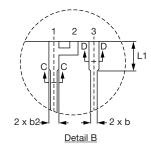
-A1

plane

DIMENSIONS in millimeters and inches









Conforms to JEDEC[®] outline TO-220AC

⊕ 0.015 BA

| SYMBOL | MILLIMETERS | | INCHES | | NOTES | NOTES | | SYMBOL | MILLIN | IETERS | INC | HES | NOTES |
|----------|-------------|-------|--------|-------|-------|---------|------|--------|--------|--------|-------|------|-------|
| STIVIDUL | MIN. | MAX. | MIN. | MAX. | NOTES | STWIDUL | MIN. | MAX. | MIN. | MAX. | NOTES | | |
| А | 4.25 | 4.65 | 0.167 | 0.183 | | | E1 | 6.86 | 8.89 | 0.270 | 0.350 | 6 | |
| A1 | 1.14 | 1.40 | 0.045 | 0.055 | | | E2 | - | 0.76 | - | 0.030 | 7 | |
| A2 | 2.56 | 2.92 | 0.101 | 0.115 | | | e1 | 4.88 | 5.28 | 0.192 | 0.208 | | |
| b | 0.69 | 1.01 | 0.027 | 0.040 | | | H1 | 5.84 | 6.86 | 0.230 | 0.270 | 6, 7 | |
| b1 | 0.38 | 0.97 | 0.015 | 0.038 | 4 | | L | 13.52 | 14.02 | 0.532 | 0.552 | | |
| b2 | 1.20 | 1.73 | 0.047 | 0.068 | | | L1 | 3.32 | 3.82 | 0.131 | 0.150 | 2 | |
| b3 | 1.14 | 1.73 | 0.045 | 0.068 | 4 | | L3 | 1.78 | 2.13 | 0.070 | 0.084 | | |
| с | 0.36 | 0.61 | 0.014 | 0.024 | | | L4 | 0.76 | 1.27 | 0.030 | 0.050 | 2 | |
| c1 | 0.36 | 0.56 | 0.014 | 0.022 | 4 | | ØΡ | 3.54 | 3.73 | 0.139 | 0.147 | | |
| D | 14.85 | 15.25 | 0.585 | 0.600 | 3 | | Q | 2.60 | 3.00 | 0.102 | 0.118 | | |
| D1 | 8.38 | 9.02 | 0.330 | 0.355 | | | | | | | | | |
| D2 | 11.68 | 12.88 | 0.460 | 0.507 | 6 | | | | | | | | |
| E | 10.11 | 10.51 | 0.398 | 0.414 | 3, 6 | | | | | | | | |

Notes

⁽¹⁾ Dimensioning and tolerancing as per ASME Y14.5M-1994

⁽²⁾ Lead dimension and finish uncontrolled in L1

(3) Dimension D, D1 and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outermost extremes of the plastic body

- (4) Dimension b1, b3 and c1 apply to base metal only
- ⁽⁵⁾ Controlling dimension: inches
- ⁽⁶⁾ Thermal pad contour optional within dimensions E, H1, D2 and E1

⁽⁷⁾ Dimension E2 x H1 define a zone where stamping and singulation irregularities are allowed

⁽⁸⁾ Outline conforms to JEDEC TO-220, D2 (minimum) where dimensions are derived from the actual package outline

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